

Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors
- Halogen Free. "Green" Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

NPN Digital Transistor

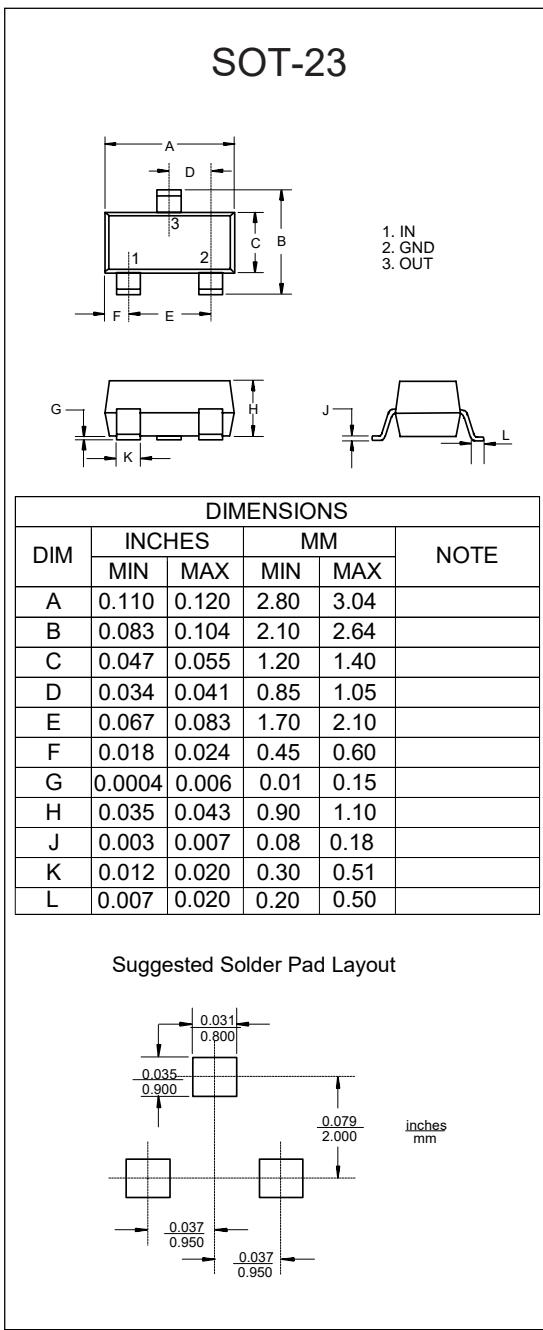
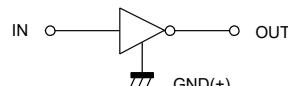
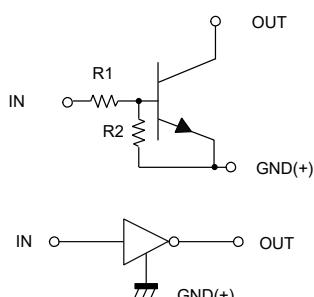
Maximum Ratings @ 25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V _{CC}	---	50	---	V
Input Voltage	V _{IN}	-5	---	+12	V
Output Current	I _O	---	100	---	mA
	I _{c(Max)}	---	100	---	mA
Power Dissipation	P _D	---	200	---	mW
Junction Temperature	T _J	---	---	150	°C
Storage Temperature	T _{stg}	-55	---	150	°C

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Device Marking: E42

Internal Structure



Electrical Characteristics @ 25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input Voltage	$V_{I(\text{off})}$	0.5	---	---	V	$V_{CC}=5V, I_O=100\mu A$
	$V_{I(\text{on})}$	---	---	1.1	V	$V_O=0.3V, I_O=5mA$
Output Voltage	$V_{O(\text{on})}$	---	0.1	0.3	V	$I_O=5mA, I_I=0.25mA$
Input Current	I_I	---	---	3.6	mA	$V_I=5V$
Output Current	$I_O(\text{off})$	---	---	0.5	μA	$V_{CC}=50V, V_I=0$
DC Current Gain	G_I	80	---	---		$V_O=5V, I_O=10mA$
Input Resistance	R_I	1.54	2.2	2.86	KΩ	
Resistance Ratio	R_2/R_1	17	21	26		
Transition Frequency	f_T	---	250	---	MHz	$V_{CE}=10V, I_E=-5mA, f=100MHz$

Curve Characteristics

Fig. 1 - DC Current Gain Characteristics

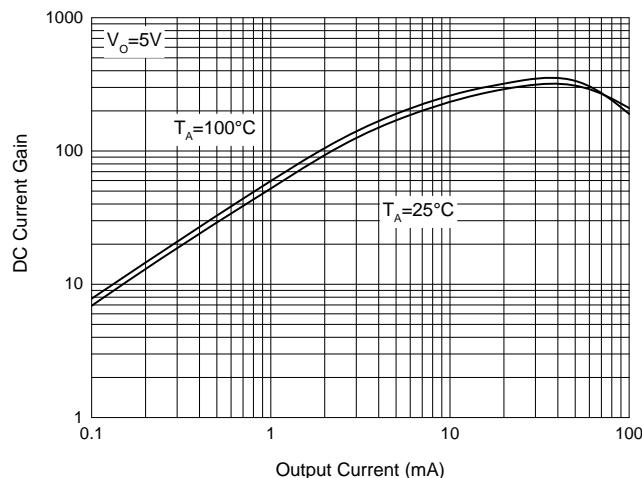


Fig. 2 - Input Voltage (on) Characteristics

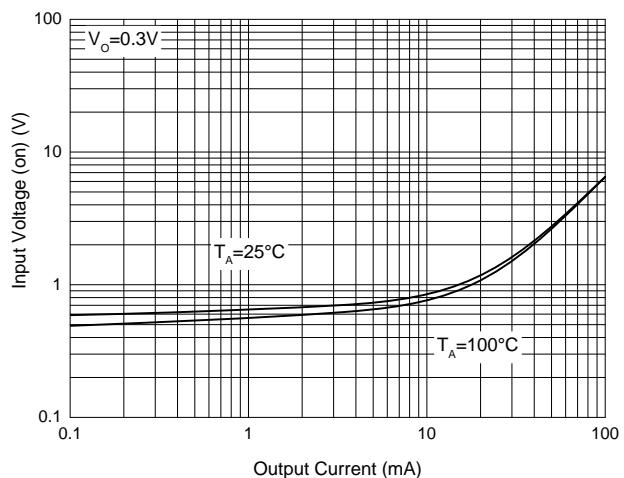


Fig. 3 - Input Voltage (off) Characteristics

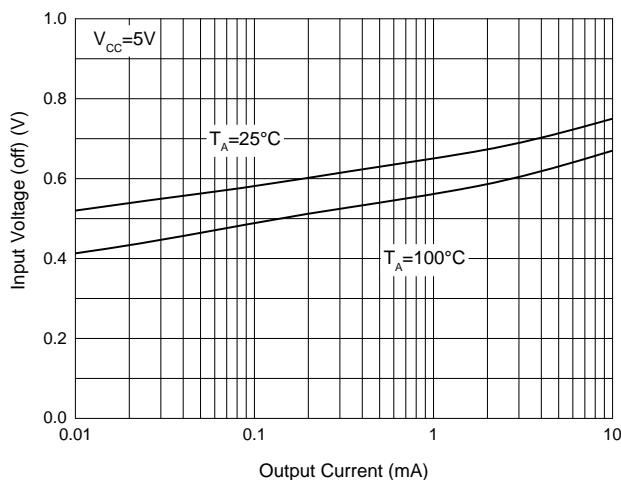


Fig. 4 - Output Voltage Characteristics

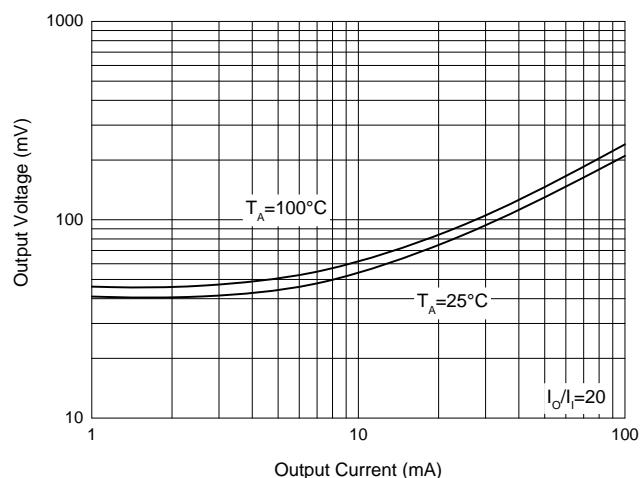


Fig. 5 - Power Derating Curve

